



# BISTAR

TP8F60M  
TP8F60M(H) **120-cell**  
W  
12BB Half-cut Mono Perc



## KEY FEATURES



### 12BB Half-cut Cell Technology

New circuit design, lower internal current, lower Rs loss  
Ga doped wafer, attenuation <2% (1st year) / ≤0.55% (Linear)



### Significantly Lower the Risk of Hot Spot

Special circuit design with much lower hot spot temperature



### Lower LCOE

2% more



### IP68 Junction Box

High waterproof level

- IEC 61215 / IEC 61730 / UL 61730
- ISO 9001: 2015 Quality Management System
- ISO 14001: 2015 Environment Management System
- ISO 45001: 2018 Occupational Health and Safety

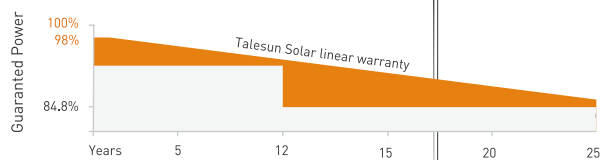


## PERFORMANCE WARRANTY

12 Years  
Quality Assurance

25 Years  
Power Output Guarantee

Linear Performance Warranty



Testing C